

S8050

TRANSISTOR (PNP)

FEATURES

Power dissipation

1. EMITTER P_{CM} : 0.625 W(Tamb=25°C)

Collector current

 I_{CM} : 0.5

Collector-base voltage

 $V_{(BR)CBO}$: 40

TO-92

ELECTRICAL CHARACTERISTICS(Tamb=25℃ unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	V(BR) _{CBO}	Ic= 100 μ A , I _E =0	40			V
Collector-emitter breakdown voltage	V(BR) _{CEO}	Ic= 0.1 mA, I _B =0	25			V
Emitter-base breakdown voltage	V(BR) _{EBO}	I _E = 100 μ A , I _C =0	5			V
Collector cut-off current	I _{CBO}	V _{CB} = 40 V , I _E =0			0.1	μА
Collector cut-off current	I _{CEO}	V _{CE} = 20 V , I _B =0			0.1	μА
Emitter cut-off current	I _{EBO}	V _{EB} = 5 V, I _C =0			0.1	μА
DC ourrent gain/note)	H _{FE(1)}	V _{CE} = 1 V, I _C = 50mA	85		300	
DC current gain(note)	H _{FE(2)}	V _{CE} = 1 V, I _C = 500mA	50			
Collector-emitter saturation voltage	V _{CE} (sat)	I _C = 500mA, I _B = 50 mA			0.6	V
Base-emitter saturation voltage	V _{BE} (sat)	I _C = 500mA, I _B = 50 mA			1.2	V
Base-emitter voltage	V _{BE}	I _E = 100mA			1.4	V
Transition frequency	f _⊤	V_{CE} = 6 V, I_{C} = 20mA f = 30MHz	150			MHz

2. BASE

3. COLLECTOR

CLASSIFICATION OF H_{FE(1)}

Rank	В	С	D		
Range	85-160	120-200	160-300		

Wing Shing Computer Components Co., (H.K.)Ltd. Homepage: http://www.wingshing.com

Tel:(852)2341 9276 Fax:(852)2797 8153 E-mail: wsccltd@hkstar.com

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